1

P-Channel 30-V (D-S) MOSFET

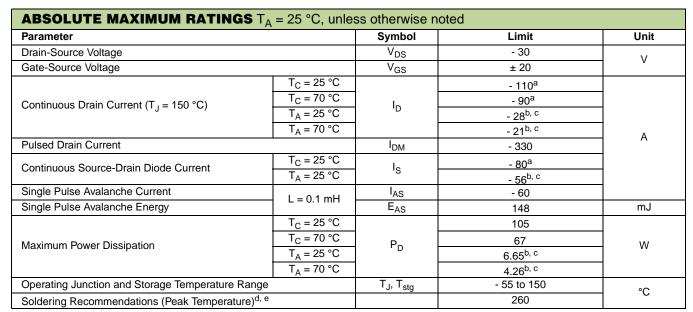
PRODUCT SUMMARY						
V _{DS} (V)	R _{DS(on)} (mΩ)	I _D (A) ^a	Q _g (Typ.)			
- 30	4.6 at V _{GS} = - 10 V	- 110	79 nC			
	7 at V _{GS} = - 4.5 V	- 90	79110			

FEATURES

- DT-Trench Power MOSFET
- 100 % R_g and UIS tested

APPLICATIONS

- Notebook
 - Load Switch



THERMAL RESISTANCE RATINGS									
Parameter	Symbol	Typical	Maximum	Unit					
Maximum Junction-to-Ambient ^{b, f}	t ≤ 10 s	R _{thJA}	15	22	°C/W				
Maximum Junction-to-Case (Drain)	Steady State	R _{thJC}	0.9	1.3	0/11				

Notes: a. Package limited.

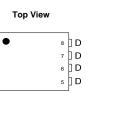
b. Surface Mounted on 1" x 1" FR4 board.

c. t = 10 s.

- d. The DFN5x6 is a leadless package. The end of the lead terminal is exposed
- copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- e. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.
- f. Maximum under Steady State conditions is 54 °C/W.

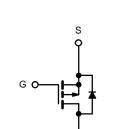
Top View Bottom View

DFN5X6



S []¹ S []²

S [] 3 G [] 4









P-Channel MOSFET

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static				•			
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = -250 \mu A$	- 30			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	V_{DS}/T_{J} I _D = - 250 µA		- 31		m)//8C	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	iD = - 200 μΛ		6.5		mV/°C	
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	- 1.0		- 3.0	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zara Cata Valtaga Drain Current	I _{DSS}	$V_{DS} = -24 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			- 1	μA	
Zero Gate Voltage Drain Current		V_{DS} = - 24 V, V_{GS} = 0 V, T_{J} = 55 °C			- 10		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 V, V_{GS} = -10 V$	- 110			Α	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 10 V, I _D = - 20 A		4.6	5.5		
		V _{GS} = - 4.5 V, I _D = - 15 A		7	8.9	mΩ	
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 20 A		97		S	
Dynamic ^b							
Input Capacitance	C _{iss}			8550		pF	
Output Capacitance	C _{oss}	V_{DS} = - 15 V, V_{GS} = 0 V, f = 1 MHz		1475			
Reverse Transfer Capacitance	C _{rss}			915			
Total Gate Charge	Qg			79		nC	
Gate-Source Charge	Q _{gs}	V_{DS} = - 15 V, V_{GS} = - 10 V, I_{D} = - 20 A		23			
Gate-Drain Charge	Q _{gd}			37			
Gate Resistance	Rg	f = 1 MHz		1.9		Ω	
Turn-On Delay Time	t _{d(on)}			25			
Rise Time	t _r	V_{DD} = - 15 V, R_L = 15 Ω		15		ns	
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ - 1.0 A, V_{GEN} = - 10 V, R_g = 1 Ω		110			
Fall Time	t _f			30			
Drain-Source Body Diode Characteristic	S						
Continuous Source-Drain Diode Current	ا _S	T _C = 25 °C			110	A	
Pulse Diode Forward Current ^a	I _{SM}				330		
Body Diode Voltage	V _{SD}	I _S = - 5 A		- 0.54	- 1.1	V	
Body Diode Reverse Recovery Time	t _{rr}			38		ns	
Body Diode Reverse Recovery Charge	Q _{rr}			75		nC	
Reverse Recovery Fall Time	ta	I _F = 3.5 A, dl/dt = 100 A/μs, T _J = 25 °C		26			
Reverse Recovery Rise Time	t _b			21		ns	

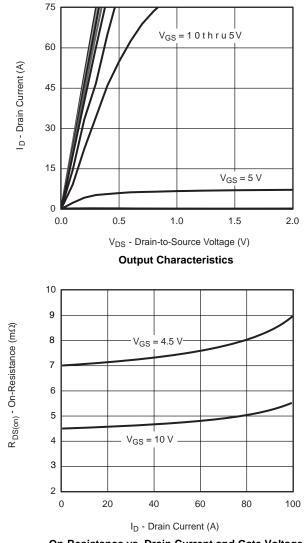
Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

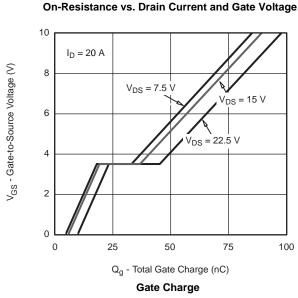
b. Guaranteed by design, not subject to production testing.

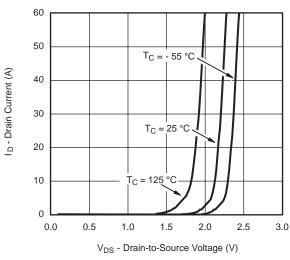
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



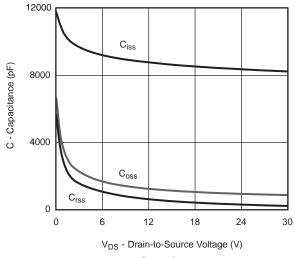


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

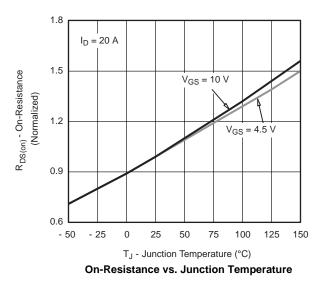




Transfer Characteristics



Capacitance





T_J = 125 °C

T_J = 25 °C

10

8 9 10

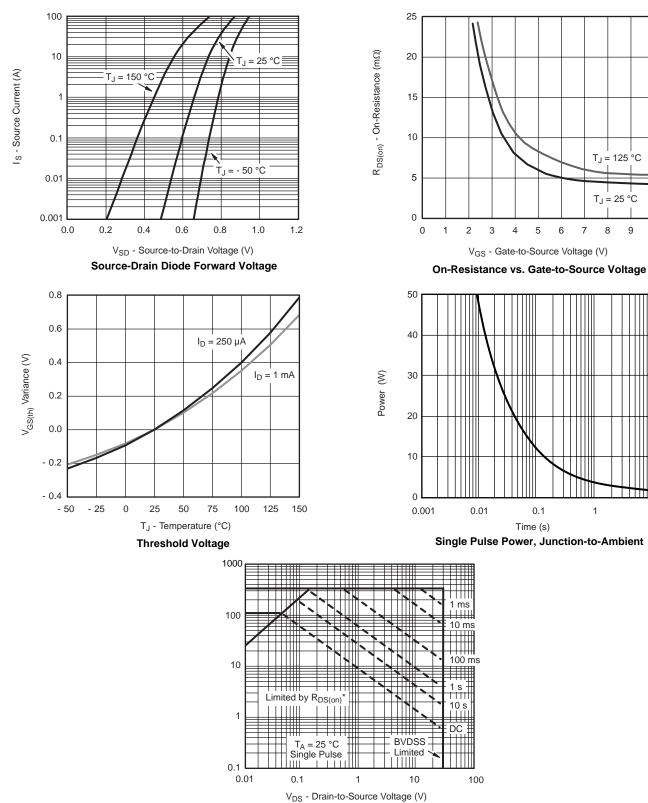
4 5 6 7

0.1

Time (s)

1

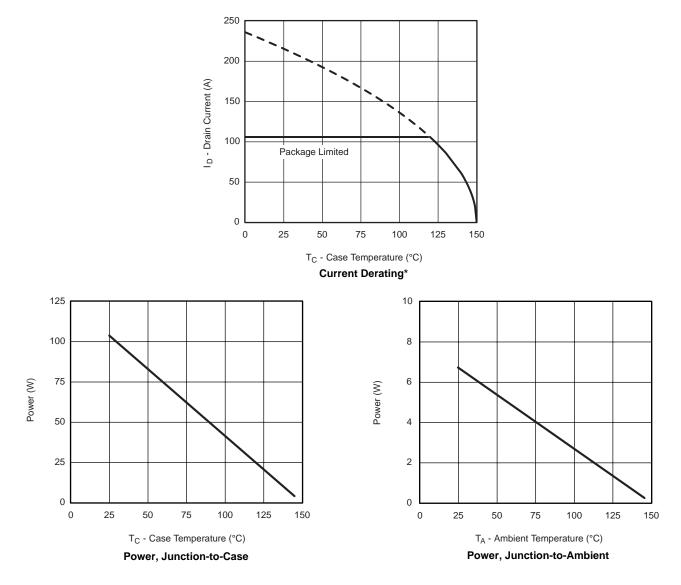
3



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



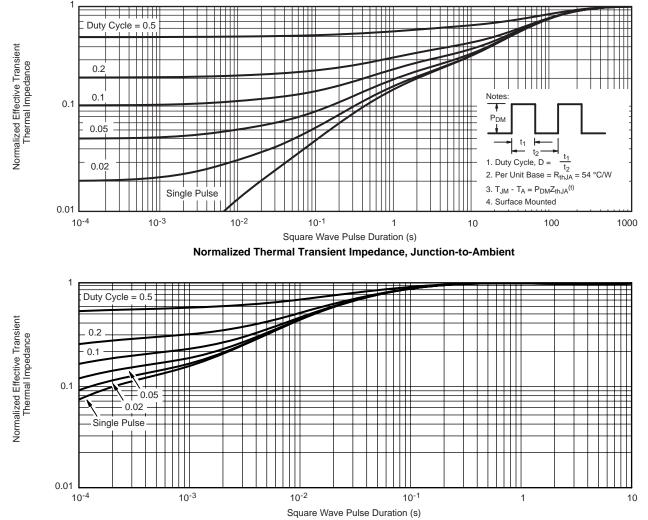
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



* The power dissipation P_D is based on $T_{J(max)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case



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